



SPE15S60E-DZ

主要参数 MAIN CHARACTERISTICS

600V/15A 三相全桥智能功率模块	
V_{CES}	600V
$\pm I_C$	15A
$\pm I_{CP}$	30A

用途

- 冰箱压缩机
- 空调压缩机
- 低功率变频器

APPLICATIONS

- Refrigerator compressor
- Air-conditioning compressor
- Low power inverter

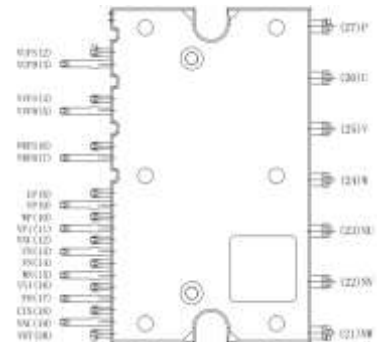
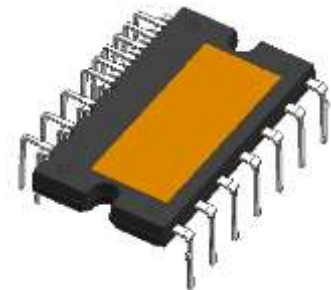
产品特性

- 下臂 IGBT 发射极输出，内置自举二极管。
- 600V/15A 三相逆变器，内置低损耗沟道栅-场截止型 IGBT。
- IGBT 驱动：高压高速电平转换，电源欠压保护，短路（过流）保护，过温保护和温度输出。
- 故障信号：对应于低侧短路（过流）、低侧电源欠压故障。
- 输入接口：兼容 3.3V & 5V 输入信号，高电平有效。

FEATURES

- Lower arm IGBT emitter output, built-in bootstrap diode.
- 600V/15A three-phase inverter with built-in low-loss trench gate-field stop IGBT.
- IGBT drive: High voltage high-speed level conversion, power supply under-voltage protection, short circuit (overcurrent) protection, Over temperature protection and temperature output.
- Fault signal: Corresponding to SC fault (Low-side IGBT), UV fault (Low-side supply).
- Input interface: compatible with 3.3V&5V input signals, high level effective.

封装 Package



DIP28-DBC

订货信息 ORDER MESSAGE

订货料号 Order number	产品信息 Product information			
	无卤-条管 Halogen-Free-Tube	无卤-编带 Halogen-Free-Reel	印记 Marking	封装 Package
2A01-1033	SPE15S60E-DZ	N/A	SPE15S60E-DZ	DIP28-DBC



模块示意图 Module diagram

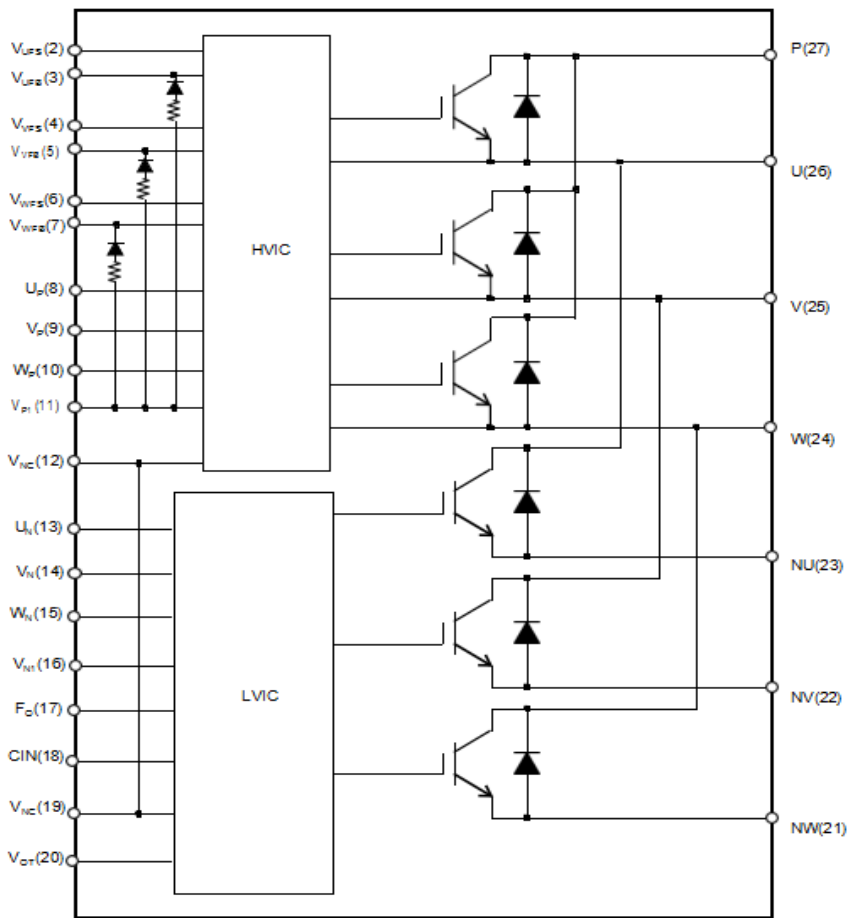


图 1：模块内部电路示意图
Fig 1: Internal circuit

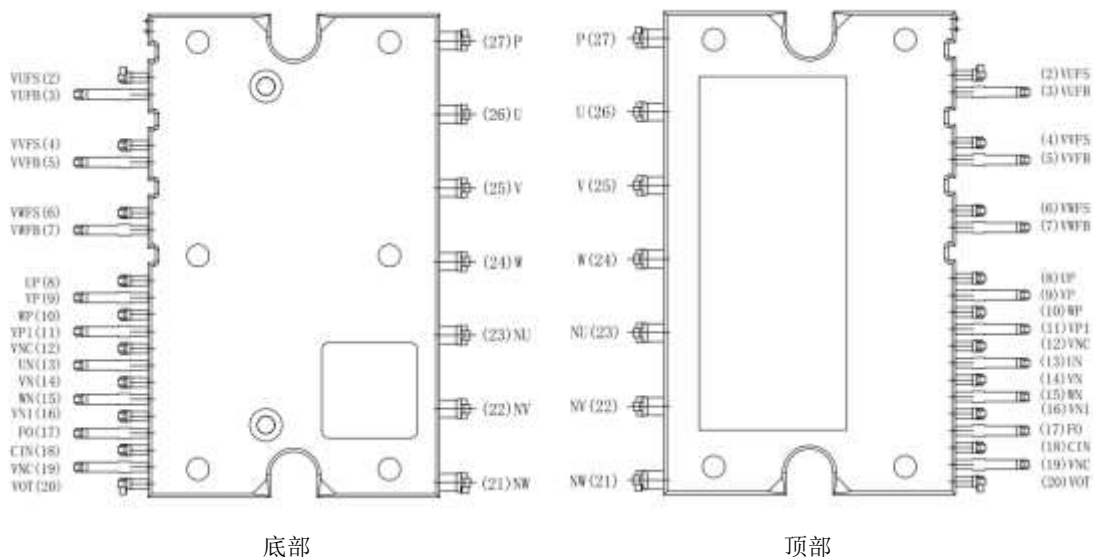


图 2：模块引脚分布示意图
Fig 2: Distribution of pin



管脚编号 Pin Number	管脚名称 Pin Names	管脚描述 Pin Description
1	NC	无连接 connectionless
2	VUFS	U 相 上臂驱动电源地端子 U-phase upper arm drive supply GND terminal
3	VUFB	U 相上臂驱动电源端子 U-phase upper arm drive power terminal
4	VVFS	V 相 上臂驱动电源地端子 V phase upper arm drive supply GND terminal
5	VVFB	V 相上臂驱动电源端子 V phase upper arm drive power terminal
6	VWFS	W相 上臂驱动电源地端子 W phase upper arm drive supply GND terminal
7	VWFB	W 相上臂驱动电源端子 W phase upper arm drive power terminal
8	UP	U 相上臂控制信号输入端子 U-phase upper arm control signal input terminal
9	VP	V 相上臂控制信号输入端子 V phase upper arm control signal input terminal
10	WP	W 相上臂控制信号输入端子 W phase upper arm control signal input terminal
11	VP1	控制电源端子 Control power terminal
12	VNC	控制电源 GND 端子 Control power GND terminal
13	UN	U 相下臂控制信号输入端子 U-phase lower arm control signal input terminal
14	VN	V 相下臂控制信号输入端子 V phase lower arm control signal input terminal
15	WN	W 相下臂控制信号输入端子 W phase lower arm control signal input terminal
16	VN1	控制电源端子 Control power terminal
17	FO	故障输出端子 Fault output terminal
18	CIN	短路保护触发电压检测端子 Short circuit protection trigger voltage detection terminal
19	VNC	控制电源 GND 端子 Control power GND terminal
20	VOT	温度检测输出端子 Temperature detection output terminal
21	NW	W 相下臂 IGBT 发射极端子 W phase lower arm IGBT emitter terminal
22	NV	V 相下臂 IGBT 发射极端子 V phase lower arm IGBT emitter terminal
23	NU	U 相下臂 IGBT 发射极端子 U phase lower arm IGBT emitter terminal
24	W	W 相输出端子 W phase output terminal
25	V	V 相输出端子 V phase output terminal
26	U	U 相输出端子 U phase output terminal
27	P	逆变器直流输入端子 Dc input terminal of inverter

图 3: 模块引脚功能定义表

Fig 3: Pin function



最大额定值 ($T_j = 25^\circ\text{C}$, 除非特殊说明)**Absolute Maximum Ratings** ($T_j = 25^\circ\text{C}$, Unless otherwise Specified)**逆变部分 Inverter Part**

记号 Mark	项目 Project	条件 Condition	额定值 Ratings	单位 Units
V_{CC}	电源电压 supply voltage	应用于 P- NU, NV, NW 之间 It applies between p-nu, NV, and NW	450	V
$V_{CC}(\text{Surge})$	电源电压 (含浪涌) Supply voltage (including surge)	应用于 P- NU, NV, NW 之间 It applies between p-nu, NV, and NW	500	V
V_{CES}	集电极-发射极间电压 Collector to emitter voltage	/	600	V
$\pm I_C$	集电极电流 Collector current	$T_C = 25^\circ\text{C}$ (T_C 测试方法见图 4) $T_C = 25^\circ\text{C}$ (see Figure 4 for T_C test method)	15	A
$\pm I_{CP}$	集电极电流 (峰值) Collector current (peak)	$T_C = 25^\circ\text{C}$, 脉冲宽度小于 1ms $T_C = 25^\circ\text{C}$, pulse width is less than 1ms	30	A
T_j	结温 Junction temperature	(见备注 1) (See note 1)	-40~+150	$^\circ\text{C}$

备注 1: IPM 功率芯片最大额定结温为 150°C (@表面温度 $T_C \leq 100^\circ\text{C}$)。然而,为了确保 IPM 运行安全,结温应限定于 $T_j(\text{av}) \leq 125^\circ\text{C}$ (@表面温度 $T_C \leq 100^\circ\text{C}$)。

Remark 1: The maximum rated junction temperature of the IPM power chip is 150°C (@surface temperature $T_C \leq 100^\circ\text{C}$).

However, to ensure safe operation of the IPM, the junction temperature should be limited to $T_j(\text{av}) \leq 125^\circ\text{C}$ (@surface temperature $T_C \leq 100^\circ\text{C}$).

控制部分 Control Part

记号 Mark	项目 Project	条件 Condition	额定值 Ratings	单位 Units
V_{DB}	上桥臂控制电源电压 Upper arm control supply voltage	应用于 UFB – UFS, VFB-VFS, WFB-WFS 之间 Applied between UFB-UFS, VFB-VFS, WFB-WFS	20	V
V_D	控制电源电压 Control supply voltage	应用于 VP1 – VNC 之间, VN1 – VNC 之间 Applied between VP1-VNC, VN1 – VNC	20	V
V_{IN}	输入信号电压 Input signal voltage	应用于 UP, VP, WP, UN, VN, WN-VNC 之间 Applied between UP, VP, WP, UN, VN, WN-VNC	-0.5~ V_D +0.5	V
V_{FO}	故障输出电压 Fault output voltage	应用于 FO – V_{NC} 之间 Applied between FO-VNC	-0.5~ V_D +0.5	V
I_{FO}	故障输出电流 Fault output current	FO 端子吸入电流值 FO terminal sink current value	1.5	mA
V_{SC}	电流检测端输入电压 Input voltage of current detection terminal	应用于 CIN – V_{NC} 之间 Applied between CIN-VNC	-0.5~ V_D +0.5	V





整个系统 Total System

记号 Mark	项目 Project	条件 Condition	额定值 Ratings	单位 Units
$V_{CC(prot)}$	电源电压自己保护范围（短路） Power supply voltage self-protection range (short circuit)	$V_D = V_{DB} = 13.5 \sim 16.5V$ $T_j = 150^{\circ}C$, 无重复, 时间小于 2us $T_j = 150^{\circ}C$, no repetition, time is less than 2us	400	V
T_c	模块正常工作壳体温度 Module working temperature	$-30^{\circ}C \leq T_j \leq 150^{\circ}C$	$-30 \sim +100$	$^{\circ}C$
T_{stg}	贮存温度 Storage temperature	/	$-40 \sim +125$	$^{\circ}C$
Viso	绝缘耐压 Insulation withstand voltage	正弦波60Hz, AC 1分钟, 在插脚和散热片之间 Sine wave 60Hz, AC for 1 minute, between pin and heat sink	2000	Vrms

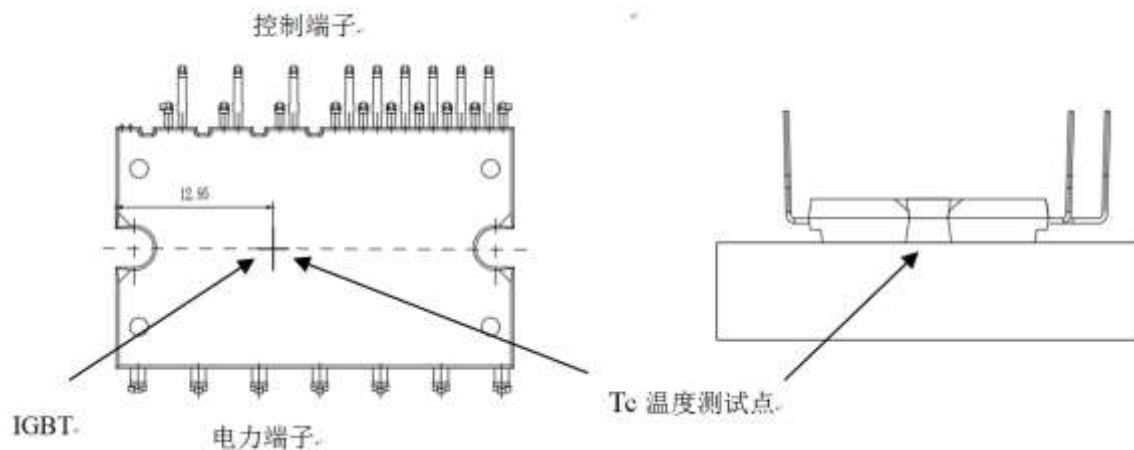
图 4: 壳温 T_c 测试点

Fig 4: Case Temperature Measurement

热阻 Thermal Resistance

记号 Mark	项目 Project	条件 Condition	最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
$R_{th(j-c)Q}$	结点到壳的热阻 Junction to case thermal resistance	单个 IGBT 元件 Single IGBT element	-	-	3.9	$^{\circ}C/W$
$R_{th(j-c)F}$		单个 FRD 元件 Single FRD element	-	-	4.3	$^{\circ}C/W$

电气特性 (T_j=25°C, 除非特殊说明)Electrical Characteristics (T_j=25°C, Unless Otherwise Specified)

逆变部分 Inverter Part

记号 Mark	项目 Project	条件 Condition	最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
V _{CE(sat)}	集电极与发射极间饱和电压 Saturation voltage between collector and emitter	V _D = V _{DB} = 15V V _{IN} = 5V, I _C = 15A, T _j = 25°C	-	1.9	2.4	V
		V _D = V _{DB} = 15V V _{IN} = 5V, I _C = 15A, T _j = 125°C	-	2.05	-	V
V _F	FWD 正向导通电压 FWD forward voltage	V _{IN} = 0V, I _C = -15A, T _j = 25°C	-	1.8	2.4	V
t _{ON}	开关时间 (备注 2) Switching time (Note 2)	V _{CC} = 300V, V _D = V _{DB} = 15V, I _C = 15A V _{IN} = 0V-5V, 感性负载	-	800	-	ns
t _{C(ON)}			-	200	-	ns
t _{OFF}			-	650	-	ns
t _{C(OFF)}			-	80	-	ns
t _{rr}			-	130	-	ns
I _{CES}	集电极到发射极漏电流 Collector to emitter leakage current	V _{CE} = V _{CES} T _j = 25°C	-	-	75	uA
		V _{CE} = V _{CES} T _j = 125°C	-	-	1	mA

备注 2: t_{ON} 和 t_{OFF} 包括驱动 IC 内部传输延迟时间。t_{C(ON)} 和 t_{C(OFF)} 是 IGBT 自身被内部给定门极驱动条件下的开关时间。详见图 5。

Remark 2: t_{ON} and t_{OFF} include the internal transmission delay time of the driver IC. t_{C(ON)} and t_{C(OFF)} are the switching times of the IGBT itself driven by the internally given gate. See Figure 5 for details.

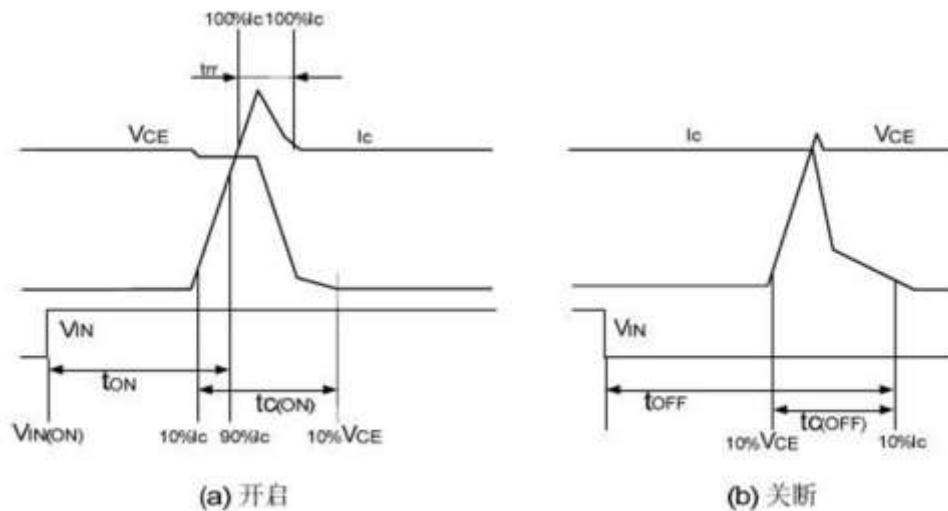


图 5: 开关时间定义

Fig 5: Switching Time Definition





控制部分 Control Part

记号 Mark	项目 Project	条件 Condition		最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
I _D	V _D 静态电流 V _D Quiescent Current	V _D = 15V V _{IN} = 5V	VP1-VNC	-	-	1	mA
I _{DB}	V _{DB} 静态电流 V _{DB} Quiescent Current	V _{DB} = 15V V _{IN} = 5V	UFB - U, VFB - V, WFB - W	-	-	550	uA
V _{FOH}	故障输出电压 Fault output voltage	V _{sc} = 0V, FO 脚通过 10K 电阻上拉至5V V _{sc} = 0V, FO pin is pulled up to 5V through 10K resistor		4.6	-	-	V
V _{FOL}		V _{sc} = 1V, I _{FO} = 1.5mA		-	-	0.3	V
V _{sc,TH+}	短路正向触发阈值 Short circuit forward trigger threshold	V _D = 15V		0.445	0.48	0.515	V
V _{sc,TH-}	短路负向触发阈值 Short circuit negative trigger threshold	V _D = 15V		0.2	0.4	-	V
UV _{DD}	电源欠压保护控制 Power undervoltage protection contro	触发电平 Trigger level		9.0	10.0	11.0	V
UV _{DR}		复位电平 Reset level		10.0	11.0	12.0	
UV _{DBD}		触发电平 Trigger level		9.0	10.0	11.0	
UV _{DBR}		复位电平 Reset level		10.0	11.0	12.0	
T _{FO}	故障输出脉冲宽度 Fault output pulse width	-		-	65	-	uS
V _{IN(ON)}	开启阈值电压 Turn on threshold voltage	应用于 UP,VP,WP,UN,VN,WN 和 VNC之间		-	2.1	2.6	V
V _{IN(OFF)}	关断阈值电压 Turn-off threshold voltage	Applied between UP, VP, WP, UN, VN, WN and VNC		1	1.4	-	
V _{OT}	温度输出, 备注 3 Temperature output, remark 3	T _c = 90℃		2.64	2.75	2.86	V
		T _c = 25℃		0.93	1.13	1.33	
OTt	过温保护 Over temperature protection	LVIC温度 LVIC temperature		100	120	140	℃
OTrh	过温保护迟滞 Over temperature protection hysteresis	LVIC迟滞温度 LVIC Hysteresis temperature		--	10	--	℃
R _{BSD}	BSD 限流电阻 Built-in limiting resistance			200	240	280	ohm

备注 3: IPM 的 VOT 输出特性曲线请参考图 6。

Remark 3: Please refer to Figure 6 for the VOT output characteristic curve of IPM.





Figure 6.1: VOT output voltage curve

Figure 6.2: V_{OT} output circuit

(1) 使用温度监测功能时，需 VOT 引脚连接下拉 5kΩ 电阻，无内部 OTP 功能；当保持 VOT 引脚悬空（无连接），可以使用内部超温停机功能，内部超温停机功能是通过检测 LVIC 温升实现的，它并不能对功率芯片的迅速升温做出有效反应。

(1) When using the temperature monitoring function, the VOT pin needs to be connected with the pull-down $5k\Omega$ resistor, and there is no internal OTP function; When keep the VOT pin open (no connection). the internal overtemperature shutdown function can be used. The internal over temperature shutdown function is realized by detecting the temperature rise of I_{vic}, which can not effectively respond to the rapid temperature rise of power chip.



(2) 在 3.3V 单片机等低压控制器上使用 VOT 时, VOT 输出在温度上升过快时, 可能超过控制电源电压 3.3V, 如果系统使用低压控制器, 建议在控制电源和 VOT 输出之间的加入钳位二极管, 用于防止过电压损坏。

(2) When using VOT on low-voltage controllers such as 3.3V single chip microcomputer, the VOT output may exceed the control power supply voltage by 3.3V when the temperature rises too fast. If the system uses low-voltage controller, it is recommended to add clamping diode between the control power supply and VOT output to prevent overvoltage damage.

推荐工作条件 Recommended Operating Conditions

记号 Mark	项目 Project	条件 Condition	最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
V _{CC}	电源电压 voltage	应用于 P – NU, NV, NW 之间 Applied between P – NU, NV, NW	0	300	400	V
V _D	控制电源电压 Control supply voltage	应用于 VP1 – VNC 之间 Applied between VP1-VNC	12.5	15	16.5	V
V _{DS}	上臂控制电源电压 Upper arm control power supply voltage	应用于 VUFB – U, VVFB – V, VWFB-W 之间 Applied between VUFB-U, VVFB-V, VWFB-W	12.5	15	16.5	V
t _{dead}	死区时间 Dead time	各桥臂输入对应, T _c ≤100℃ Corresponding to the input of each bridge arm, T _c ≤100℃	1	-	-	us
f _{PWM}	PWM 频率 PWM frequency	-20℃≤T _c ≤+100℃ -20℃≤T _j ≤+150℃	-	-	20	kHz
PWM	最小输入信号脉冲宽度 Minimum input signal pulse width	ON	0.7	-	-	us
		OFF	0.7	-	-	us
T _j	结温 Junction temperature	-	-20	-	125	℃





机械特性 Mechanical properties

项目 Project	条件 Condition	最小值 Min.	典型值 Typ.	最大值 Max.	单位 Unit
安装扭矩 Installation torque	螺丝钉尺寸: M3 Screw size: M3	-	0.69	-	N·m
设计平面度 Design flatness	见图 7 Figure 7	-30	-	+80	um
重量 weight	-	-	6	-	g

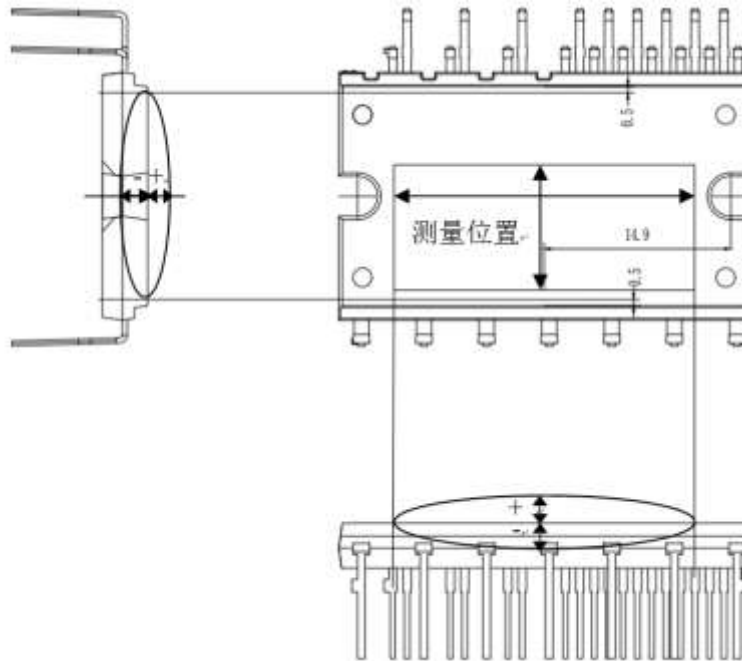


图 7: 平面度检测位置

Figure 7: Flatness detection position

应用指南 Application Guide

保护功能时序图 Timing diagram of protection function

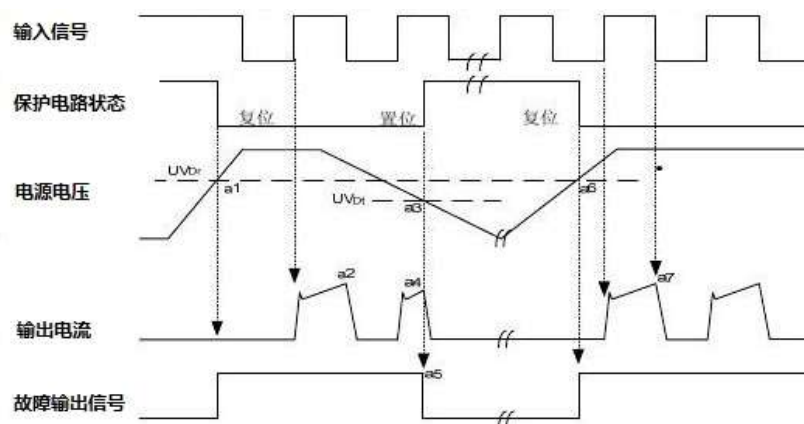


图 10: 欠压保护时序图(低侧)

Figure 10: Timing diagram of undervoltage protection (low side)

- a1: 电源电压上升: 当该电压上升到欠压恢复点, 在下一个欠压信号被执行前该线路将启动运行。
a1: Power supply voltage rise: When the voltage rises to the undervoltage recovery point, the line will start running before the next undervoltage signal is executed.
- a2: 正常运行: IGBT 开启并加载电流。
a2: Normal operation: IGBT turns on and loads current.
- a3: 欠压检测点(UVDt)。
a3: Undervoltage detection point (UVDt).
- a4: 不管输入是什么信号, IGBT 都是关闭状态。
a4: No matter what signal is input, the IGBT is off.
- a5: 故障输出开启。
a5: Fault output is on.
- a6: 欠压恢复(UVDr)。
a6: Undervoltage recovery (UVDr).
- a7: 正常运行: IGBT 导通并加载负载电流。
a7: Normal operation: IGBT is turned on and load current is loaded.

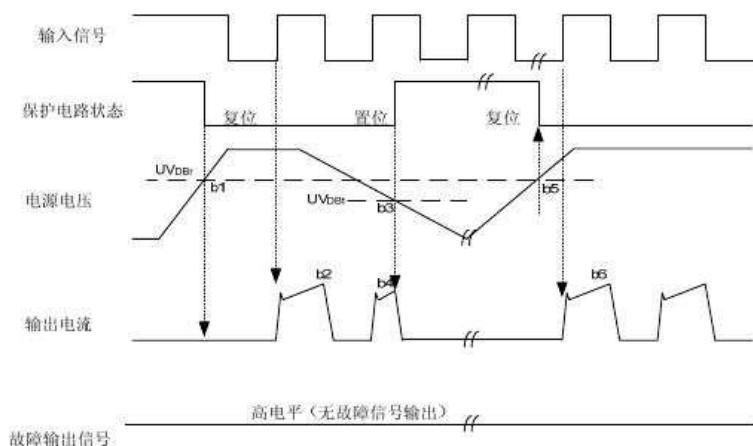


图 11: 欠压保护时序图 (高侧)

Figure 11: Timing diagram of undervoltage protection (high side)

- b1: 电源电压上升: 当该电压上升到欠压恢复点, 在下一个欠压信号被执行前该线路将启动运行。
b1: Power supply voltage rise: When the voltage rises to the undervoltage recovery point, the line will start running before the next undervoltage signal is executed.
- b2: 正常运行: IGBT 导通并加载负载电流。
b2: Normal operation: IGBT is turned on and load current is applied.
- b3: 欠压检测 (UVDBt)。
b3: Undervoltage detection (UVDBt).
- b4: 不管输入是什么信号, IGBT 都是关闭状态。
b4: No matter what signal is input, IGBT is off.
- b5: 欠压恢复(UVDBr)。
b5: Undervoltage recovery (UVDBr).

b5: Undervoltage recovery (UVDBr).

b6: 正常运行: IGBT 导通并加载负载电流。

b6: Normal operation: IGBT is turned on and load current is applied.

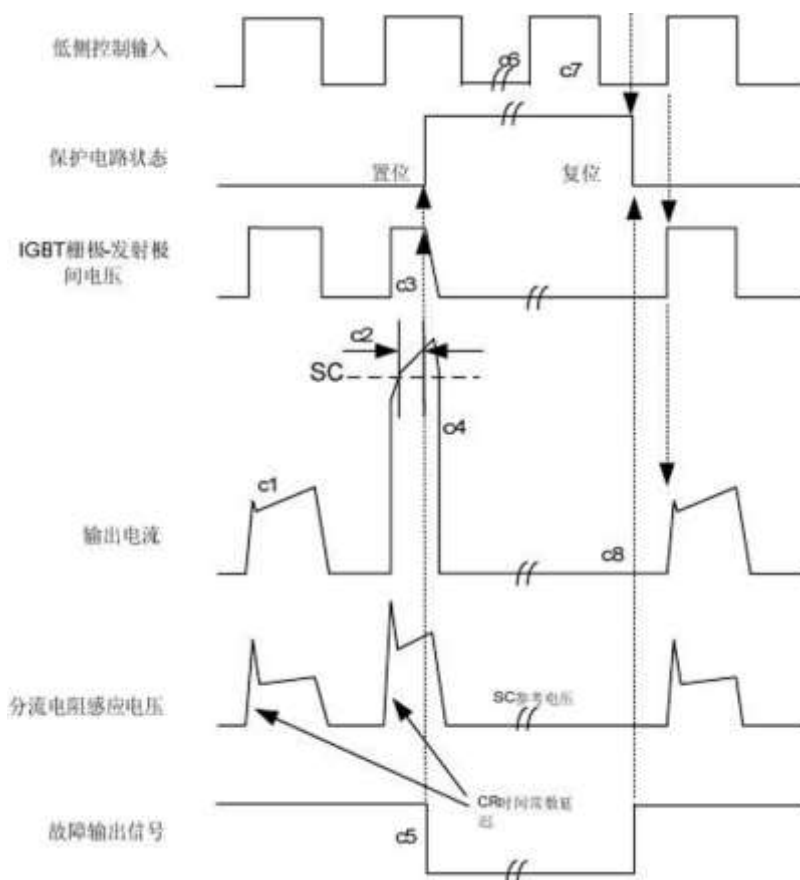


图 12: 短路电流保护时序图 (只适合于低侧)

(通过外部分流电阻连接)

Figure 12: Timing diagram of short-circuit current protection (only suitable for low side)

(Connected via external shunt resistor)

c1: 正常运行: IGBT 导通载流。

c1: Normal operation: IGBT conducting current.

c2: 短路电流检测 (CIN 触发器)。

c2: Short-circuit current detection (CIN trigger).

c3: IGBT 门极被强制关断。

c3: IGBT gate is forcibly turned off. c4: IGBT is turned off.

c4: IGBT 关断。

c4: IGBT is turned off.

c5: 故障输出定时器开始运行: 故障输出信号的脉冲宽度是 $T_{FO}=65\mu s$ 。

c5: The fault output timer starts to run: The pulse width of the fault output signal is $T_{FO}=65\mu s$.

c6: 输入“L”: IGBT 关闭。

c6: Input "L": IGBT is off.

c7: 输入“H”: IGBT 开通, 但是故障信号作用期间, IGBT 不导通。

c7: Input "H": The IGBT is turned on, but the IGBT is not turned on during the fault signal.

c8: IGBT 关断。

c8: IGBT is turned off.

输入/输出接口电路 Input/output interface circuit

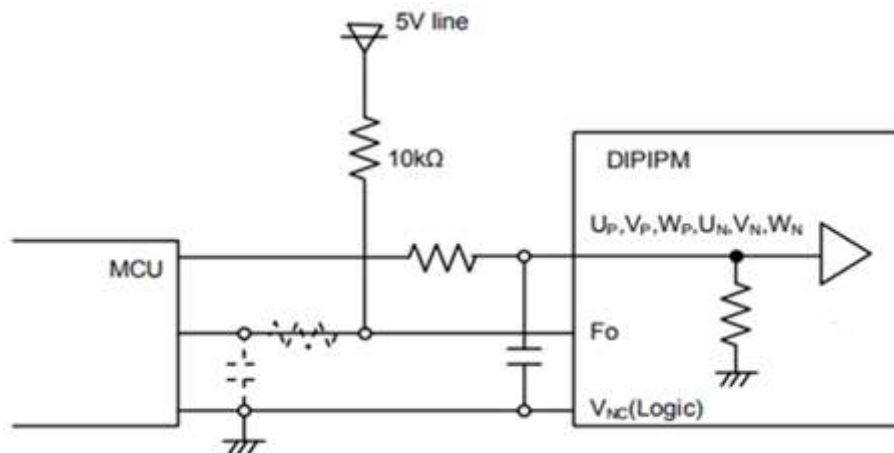


图 13: 推荐的 MCU 输入输出接口电路

Figure 13: Recommended MCU input and output interface circuit

备注 4: 由于 PWM 的控制方式和实际应用电路的阻抗及线路板的阻抗, RC 去耦可能会有变化。

Note 4: Due to the PWM control method and the impedance of the actual application circuit and the impedance of the circuit board, RC decoupling may change.

备注 5: 逻辑输入要和标准的 CMOS 或 LSTTL 输出相匹配。

Note 5: The logic input must match the standard CMOS or LSTTL output.

分流电阻接线 Shunt resistor wiring

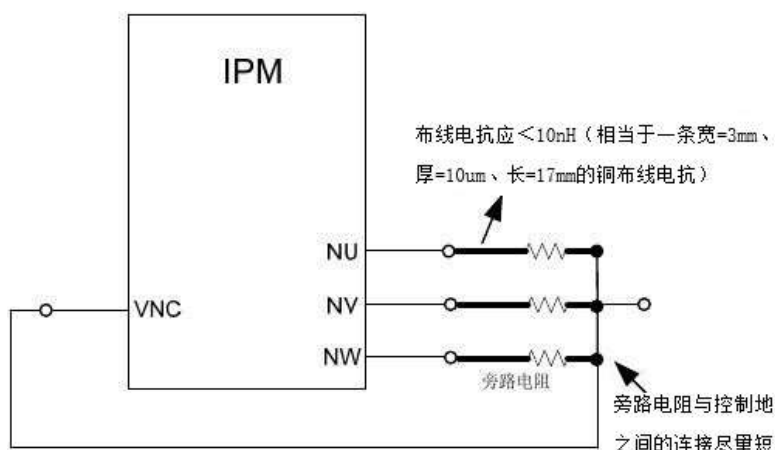


图 14: 旁路电阻接线注意事项

Figure 14: Precautions for bypass resistance wiring

**短路安全工作区 SCSOA**

条件: $V_{CC}=400V, T_j=125^{\circ}C$ (短路发生前), 非反复操作

Conditions: $V_{CC}=400V, T_j=125^{\circ}C$ at initial state, non-repetitive

此种情况下, 当 IGBT 导通小于 $3\mu s$ 时, SPE15S60E-DZ 能够可靠关断不超过 5 倍额定电流值的短路电流。由于短路安全工作区(SCSOA)会随控制电源电压(V_D)、直流母线电压(V_{CC})等的不同而变化, 因此, 设定 RC 滤波器的时间常数时要考虑一定的裕量。

In this case, when the IGBT conduction time is less than $3\mu s$, SPE15S60F-DZ can reliably turn off short-circuit currents that do not exceed 5 times the rated current value. Since the SCSOA operation area will vary with the control supply voltage, DC-link voltage, and etc, it is necessary to set time constant of RC filter with a margin.

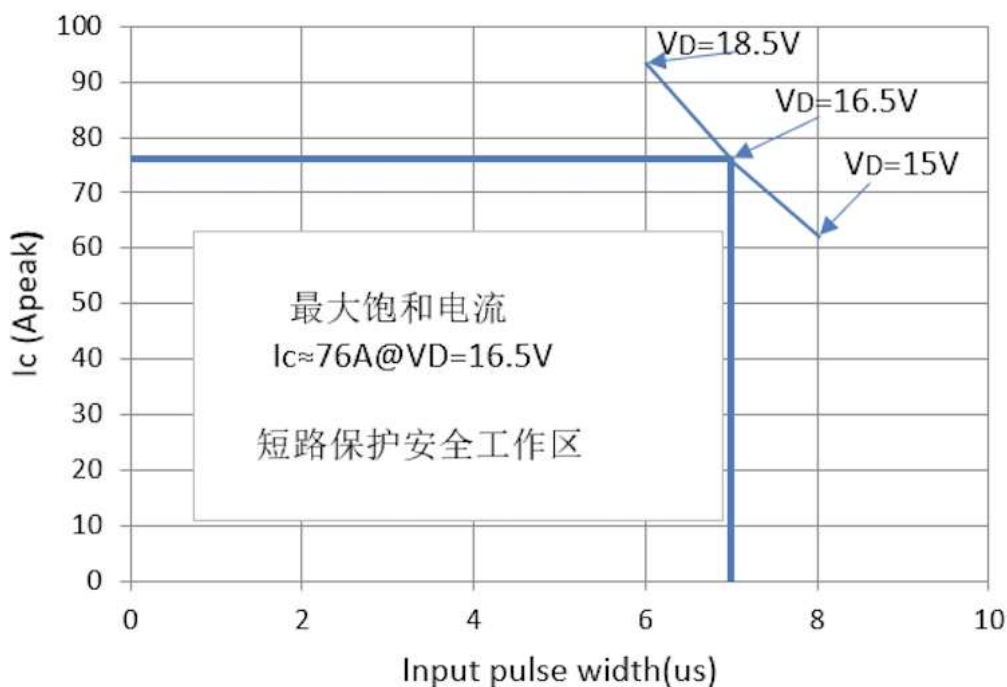


图 15 短路安全工作区曲线

Figure 15: SCSOA curve





典型应用电路图 Typical application circuit diagram

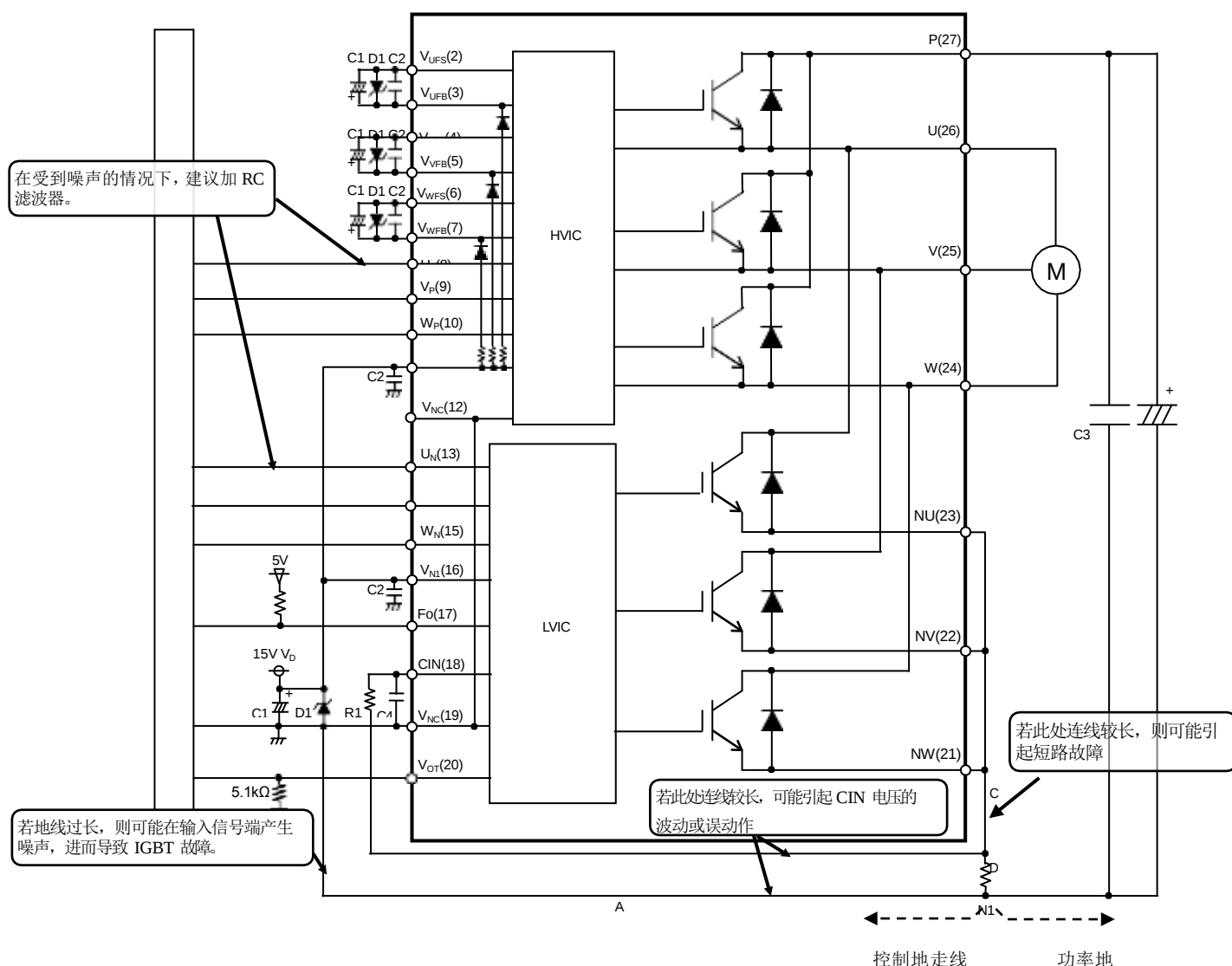


图 16: 典型应用电路

Figure 16: Typical application circuit

备注 6: 由于模块内置了专用 HVIC, 其控制端子可与 CPU 端子直接相连, 而不需要任何光耦或变压器等隔离电路。

Remark 6: Since the module has a built-in dedicated HVIC, its control terminal can be directly connected to the CPU terminal without any isolation circuit such as optocoupler or transformer.

备注 7: 为了避免浪涌损坏, 建议在每对控制电源端子近旁加入一个齐纳二极管 D1(24V/1W)。

Remark 7: It is recommended to insert a Zener diode D1(24V/1W) between each pair of control supply terminals to prevent surge destruction.

备注 8: 为了避免浪涌损坏, 平滑电容与 P 和 N1 端子之间的接线应尽可能短, 通常推荐在 P 和 N1 间加一个 0.1~0.22 μ F 的吸收电容 C3。



Remark 8: To prevent surge destruction, the wiring between the smoothing capacitor and the P, N1 terminals should be as short as possible. Generally a snubber capacitor C3 (0.1~0.22 μ F) between the P-N1 terminals is recommended.

备注 9: 保护线路 R1、C4 的时间常数建议选取在 1.5~2 μ S。关断时间可能随着布线的不同而多少有些变化。建议 R1、C4 选择小容差，温度补偿类型。

Remark9: The time constant of protection lines R1 and C5 is recommended to be 1.5~2 μ S. The turn-off time may vary somewhat depending on the wiring. It is recommended that R1 and C5 choose small tolerance and temperature compensation type.

备注 10: 为防止误保护，A、B、C 连线应尽可能短。

Note 10: To prevent false protection, the A, B, and C wiring should be as short as possible.

备注 11: 引向 CIN 滤波器的走线的分叉点 D 应靠近旁路电阻的端子。NU/NV/NW 端子与旁路电阻间的连线应尽可能短。

Remark 11: The point D at which the wiring to CIN filter is divided should be near the terminal of shunt resistor. NU, NV, NW terminals should be connected at near NU, NV, NW terminals.

备注 12: 所有电容的位置尽可能的靠近 IPM。

Remark 12: Position all capacitors as close to IPM as possible.

备注 13: 输入驱动高有效；IC 内部集成有一个下拉电阻；为防止发生误动作，输入布线应尽可能短；当用 RC 去耦线路时，须确保输入信号达到开启和关断阈值电压范围。

Remark 13: The input drive is highly effective; a pull-down resistor is integrated inside the IC; in order to prevent malfunctions, the input wiring should be as short as possible; when using RC decoupling lines, make sure that the input signal reaches on and off Threshold voltage range.

备注 14: FO 是漏极开路型，其信号线应通过一个约 10k Ω 的上拉电阻上拉到+5V/3.3V 电源。

Remark 14: FO is an open-drain type, and its signal line should be pulled up to a +5V/3.3V power supply through a pull-up resistor of about 10k Ω .

备注 15: 两个 VNC 端（12&19 脚）在 IPM 内部已连接在一起，外部任一 VNC 端子连接到 GND，另一端子允许开路。

Remark 15: The two VNC terminals (pins 9 & 16) are connected together inside the IPM, any external VNC terminal is connected to GND, and the other terminal is allowed to open.

备注 16: 如果控制地通过 PCB 走线被连接到功率地，控制信号可能会受到功率地的起伏的影响，推荐使用单点连接。

Remark 16: If the control ground is connected to the power ground through PCB traces, the control signal may be affected by the fluctuation of the power ground. It is recommended to use a single point connection.





DIP28-DBC

单位: mm

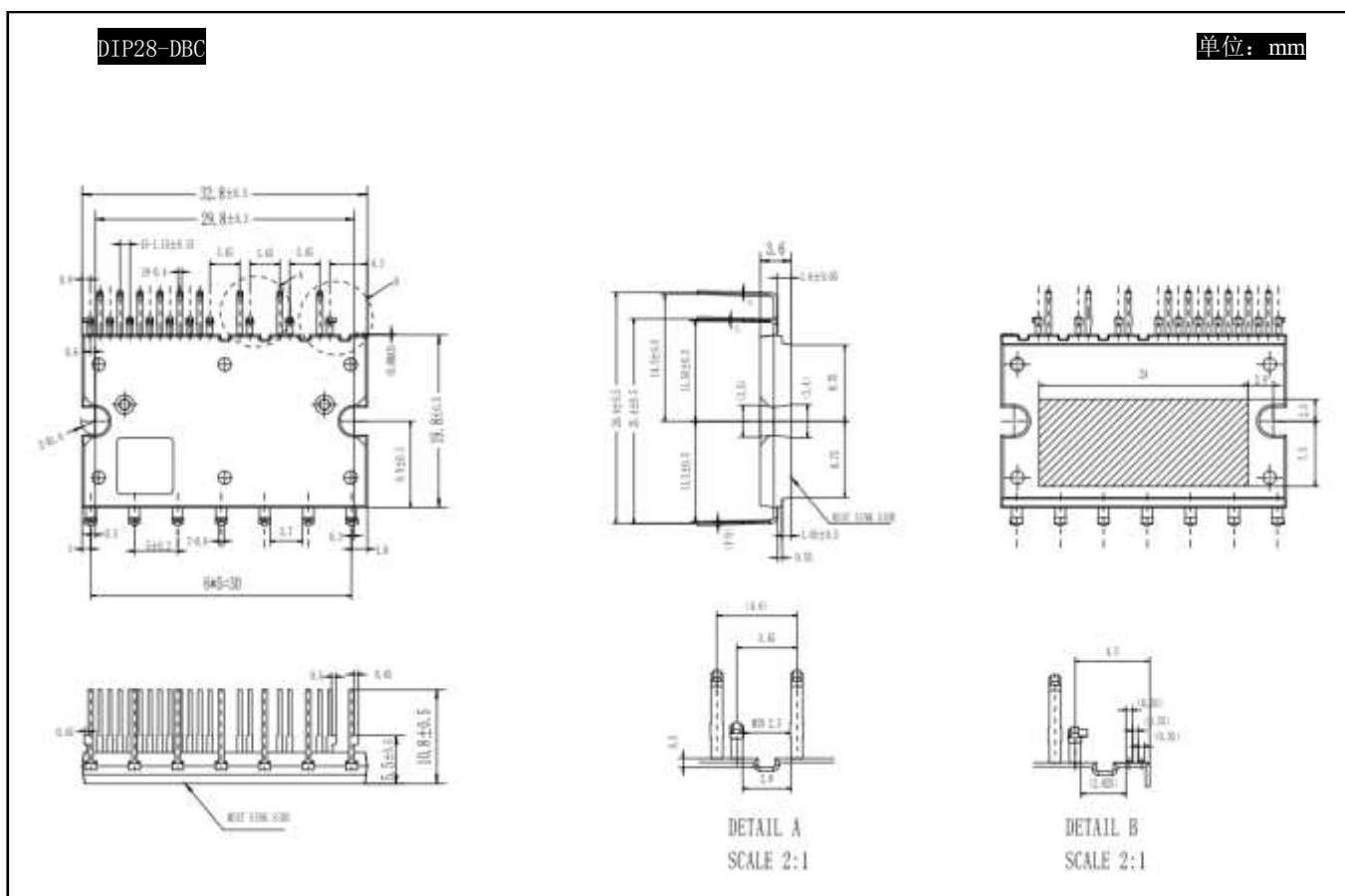


图 18: 封装尺寸示意图

Figure 16: Schematic diagram of package size





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